



ALPHA & OMEGA
SEMICONDUCTOR

AO4840

40V Dual N-Channel MOSFET

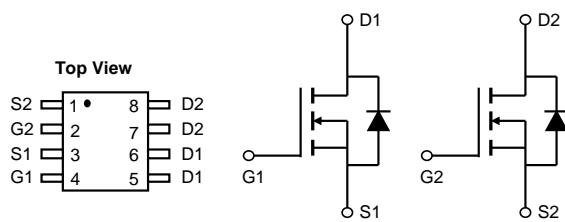
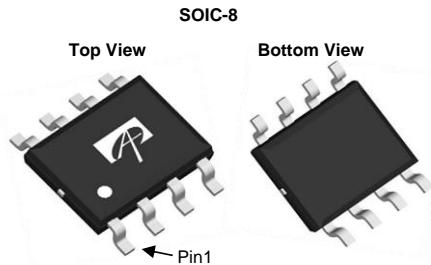
General Description

The AO4840 uses advanced trench technology MOSFETs to provide excellent $R_{DS(ON)}$ and low gate charge. This dual device is suitable for use as a load switch or in PWM applications.

Product Summary

V_{DS}	40V
I_D (at $V_{GS}=10V$)	6A
$R_{DS(ON)}$ (at $V_{GS}=10V$)	< 30mΩ
$R_{DS(ON)}$ (at $V_{GS}=4.5V$)	< 38mΩ

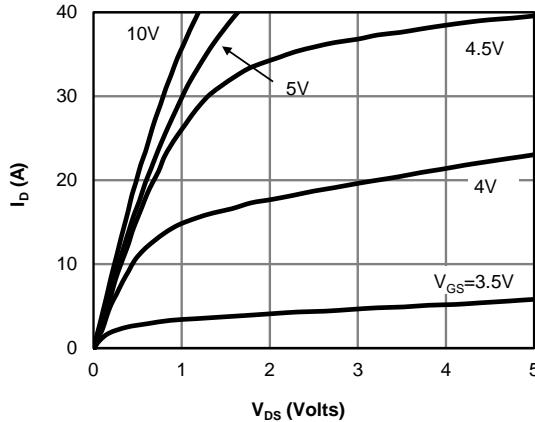
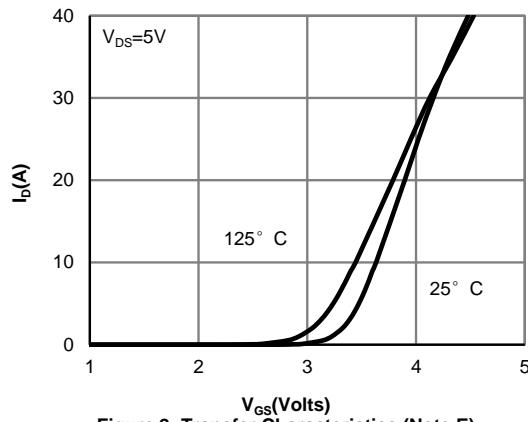
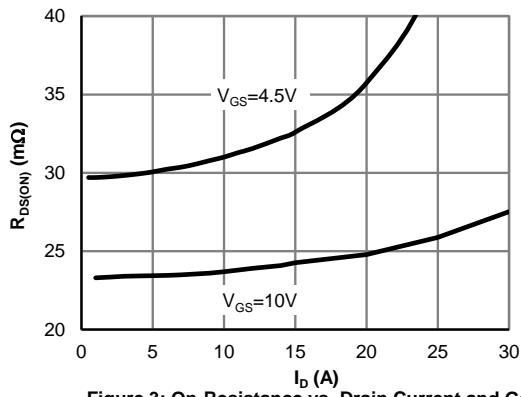
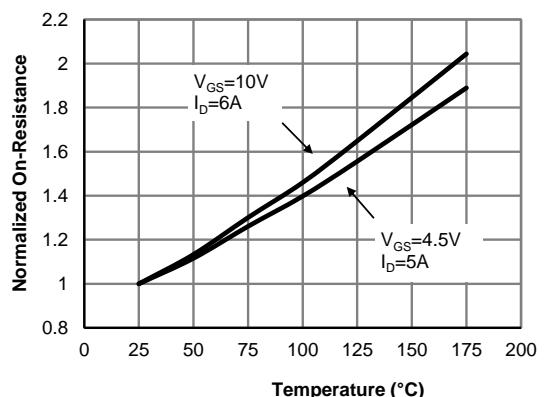
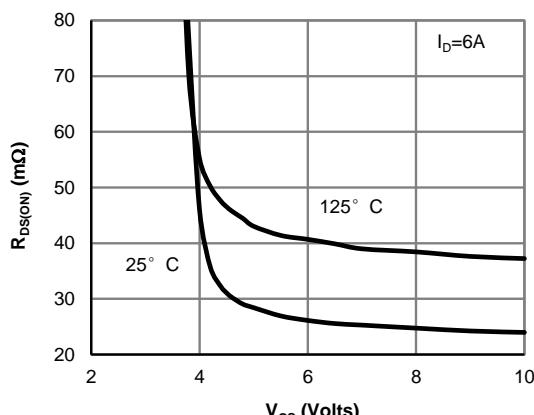
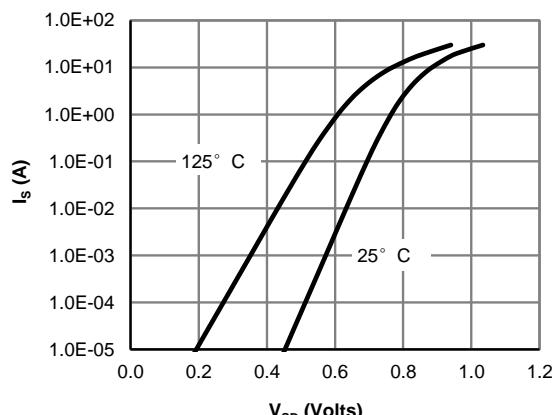
100% UIS Tested
100% R_g Tested

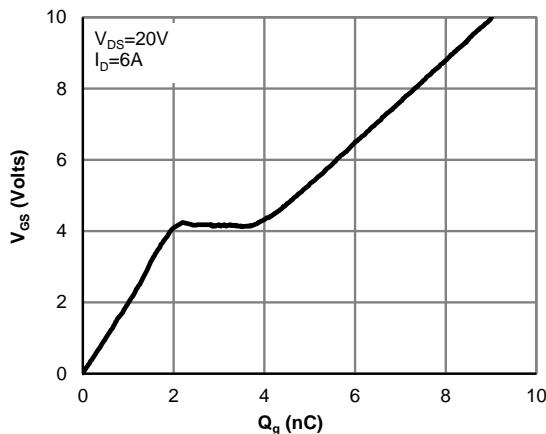
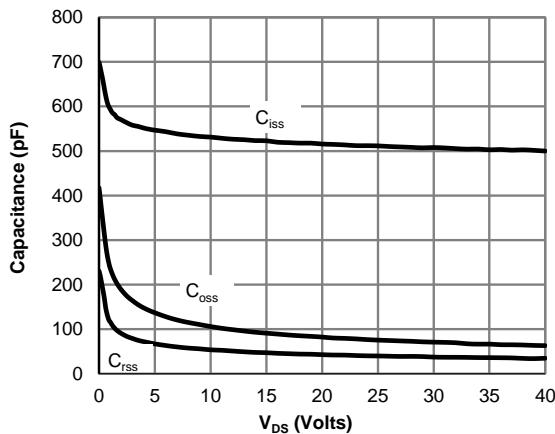
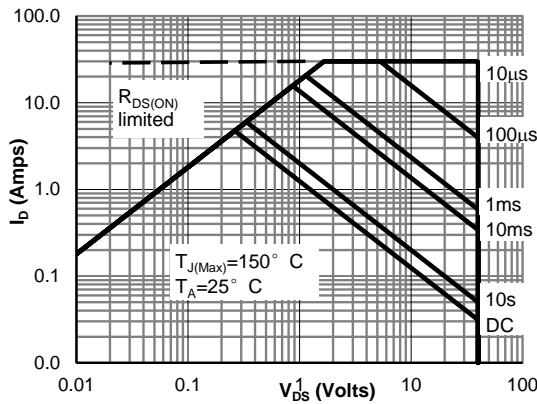
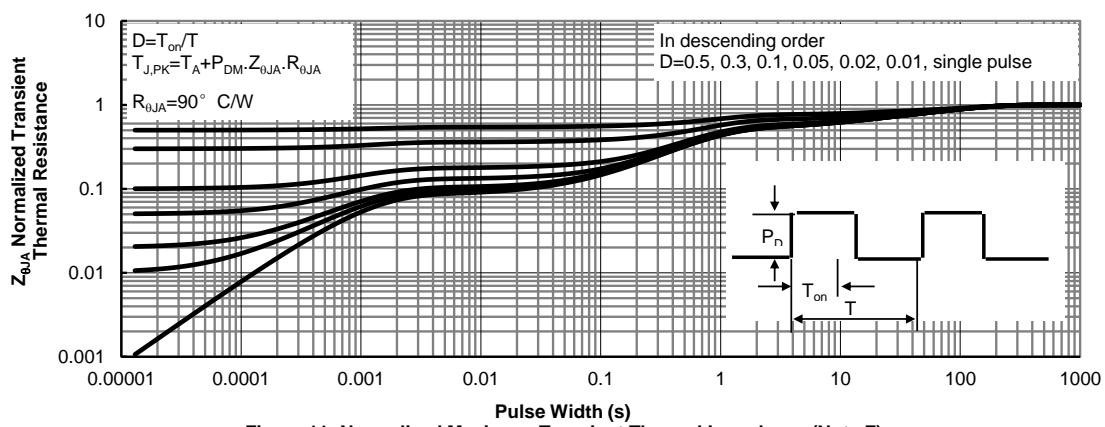
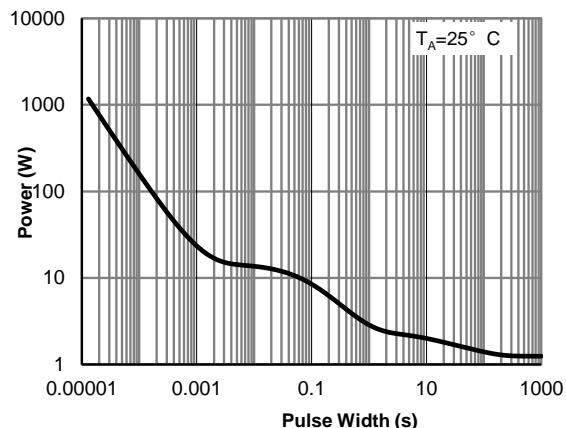


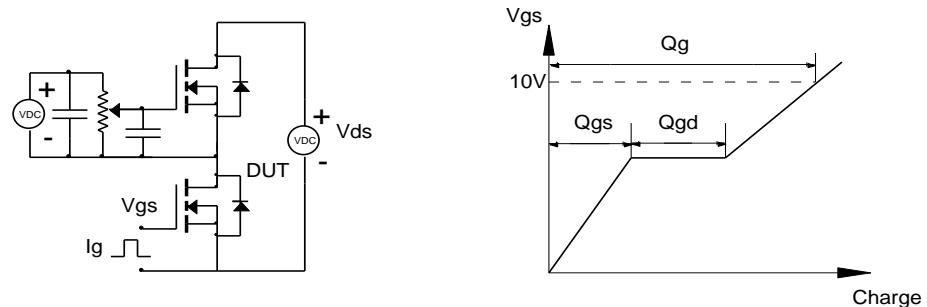
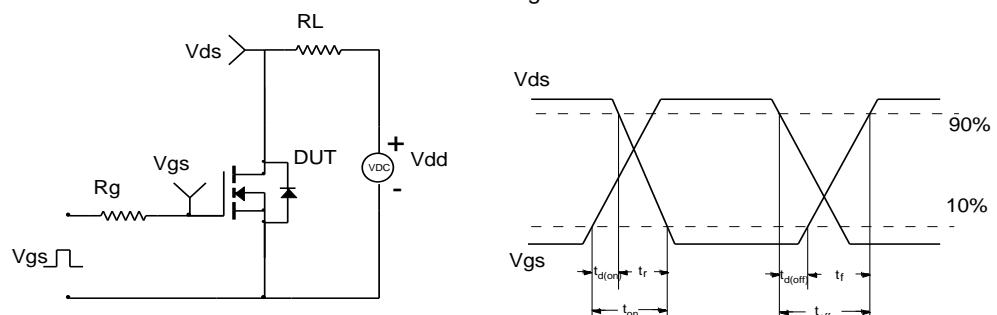
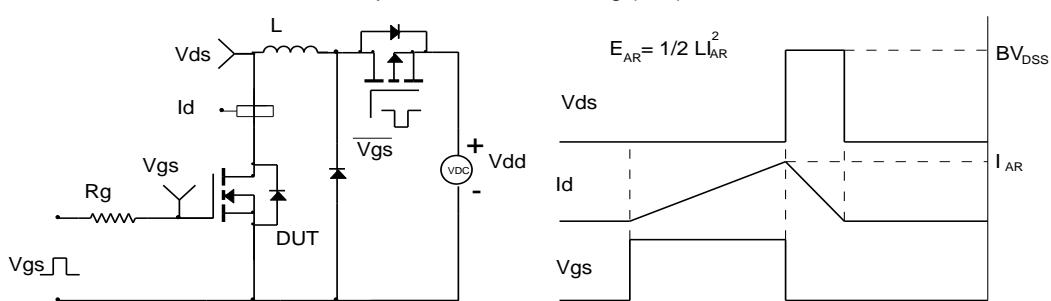
Parameter	Symbol	Maximum	Units
Drain-Source Voltage	V_{DS}	40	V
Gate-Source Voltage	V_{GS}	± 20	V
Continuous Drain Current ^A	I_D	6	A
Continuous Drain Current ^B		5	
Pulsed Drain Current ^C	I_{DM}	30	
Avalanche Current ^C	I_{AS}, I_{AR}	14	A
Avalanche energy L=0.1mH ^C	E_{AS}, E_{AR}	10	mJ
Power Dissipation ^B	P_D	2	W
Power Dissipation ^A		1.3	
Junction and Storage Temperature Range	T_J, T_{STG}	-55 to 150	°C

Thermal Characteristics

Parameter	Symbol	Typ	Max	Units
Maximum Junction-to-Ambient ^A	$R_{\theta JA}$	48	62.5	°C/W
Maximum Junction-to-Ambient ^D		74	90	°C/W
Maximum Junction-to-Lead	Steady-State	$R_{\theta JL}$	32	°C/W

TYPICAL ELECTRICAL AND THERMAL CHARACTERISTICS

Fig 1: On-Region Characteristics (Note E)

Figure 2: Transfer Characteristics (Note E)

Figure 3: On-Resistance vs. Drain Current and Gate Voltage (Note E)

Figure 4: On-Resistance vs. Junction Temperature (Note E)

Figure 5: On-Resistance vs. Gate-Source Voltage (Note E)

Figure 6: Body-Diode Characteristics (Note E)

TYPICAL ELECTRICAL AND THERMAL CHARACTERISTICS

Figure 7: Gate-Charge Characteristics

Figure 8: Capacitance Characteristics

Figure 9: Maximum Forward Biased Safe Operating Area (Note F)


Gate Charge Test Circuit & Waveform

Resistive Switching Test Circuit & Waveforms

Unclamped Inductive Switching (UIS) Test Circuit & Waveforms

Diode Recovery Test Circuit & Waveforms
